2.5V Drive Pch MOS FET

RTU002P02

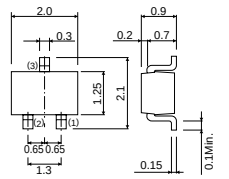
●Structure
Silicon P-channel MOS FET

●Features
1) Low On-resistance.
2) Low voltage drive (2.5V drive).

●Applications
Switching

●External dimensions (Unit : mm)

UMT3



(1) Source
(2) Gate
(3) Drain

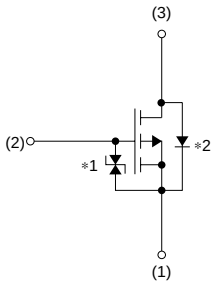
Each lead has same dimensions

Abbreviated symbol : TW

●Package specifications

Type	Package	Taping
	Code	T106
	Basic ordering unit (pieces)	3000
RTU002P02		○

●Inner circuit



∗1 ESD PROTECTION DIODE
∗2 BODY DIODE

(1) Source
(2) Gate
(3) Drain

●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DSS}	−20	V
Gate-source voltage		V_{GSS}	±12	V
Drain current	Continuous	I_D	±0.25	A
	Pulsed	I_{DP} ∗1	±0.5	A
Total power dissipation		P_D ∗2	0.2	W
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	−55 to +150	°C

∗1 Pw≤10µs, Duty cycle≤1%
∗2 Each terminal mounted on a recommended land

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a) ∗	625	°C/W

∗ Each terminal mounted on a recommended land

●**Electrical characteristics** (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	–	–	±10	μA	V_{GS}= ±12V, V_{DS}=0V
Drain-source breakdown voltage	$V_{(BR)\ DSS}$	–20	–	–	V	I_D= –1mA, V_{GS}=0V
Zero gate voltage drain current	I_{DSS}	–	–	–1	μA	V_{DS}= –20V, V_{GS}=0V
Gate threshold voltage	$V_{GS\ (th)}$	–0.7	–	–2.0	V	V_{DS}= –10V, I_D= –1mA
Static drain-source on-state resistance	$R_{DS\ (on)}$*	–	1.0	1.5	Ω	I_D= –0.25A, V_{GS}= –4.5V
		–	1.1	1.6	Ω	I_D= –0.25A, V_{GS}= –4V
		–	2.0	3.0	Ω	I_D= –0.15A, V_{GS}= –2.5V
Forward transfer admittance	$\|Y_{fs}\|$ *	0.2	–	–	S	V_{DS}= –10V, I_D= –0.15A
Input capacitance	C_{iss}	–	50	–	pF	V_{DS}= –10V
Output capacitance	C_{oss}	–	5	–	pF	V_{GS}= 0V
Reverse transfer capacitance	C_{rss}	–	5	–	pF	f=1MHz
Turn-on delay time	$t_{d\ (on)}$ *	–	9	–	ns	V_{DD}≒ –15V
Rise time	t_r *	–	6	–	ns	I_D= –0.15A
Turn-off delay time	$t_{d\ (off)}$ *	–	35	–	ns	V_{GS}= –4.5V
Fall time	t_f *	–	45	–	ns	R_L= 100Ω
						R_G= 10Ω

*Pulsed

●**Body diode characteristics** (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD}	–	–	–1.2	V	I_S= –0.1A, V_{GS}=0V

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